Schreibe die Ziffern 0 bis 9 in die folgende Tabelle:

0	1	2	3	4	5	6	7	8	9

Teil A: Schaltungsdimensionierung (2,5 Punkte)

A.1 (0.2 pt)

$V_{\text{out}} =$

A.2 (0.5 pt)

#	R_{T1}	R_{T2}	R_{T3}
$\overline{R}$			
σ_R			

A.3 (0.3 pt)
Herleitung:

A.4 (0.4 pt)

$R_\square =$ $\pm$

$\rho_{\text{Kohlenstofffilm}} =$ $\pm$

A.5 (0.5 pt)
Herleitung:

Messwerte:

$R_1 =$
$R_2 =$
$\kappa =$

A.6 (0.3 pt)

R_1 Punkte	R_x	R_y	R_2 Punkte	R_x	R_y
Z			Z		
A			H		
B			I		
C			J		
D			K		
E			L		
F			M		
G			N		
V			W		

A.7 (0.3 pt)

Punkte	V_{out}	Punkte	V_{out}
A		H	
B		I	
C		J	
D		K	
E		L	
F		M	
G		N	
V		W	

Teil B: Kennlinien des JFET-Transistors (4,0 Punkte)

B.1 (0.2 pt)
$I_{DS} =$

B.2 (0.8 pt)
I_{DS} Stromstärken:

Gate/Drain	Z	H	I	J	K	L	M	N	W
Z									
A									

B.3 (0.2 pt)

B.4 (1.2 pt)

B.4 (cont.)

B.4 (cont.)

B.4 (cont.)

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A1-9

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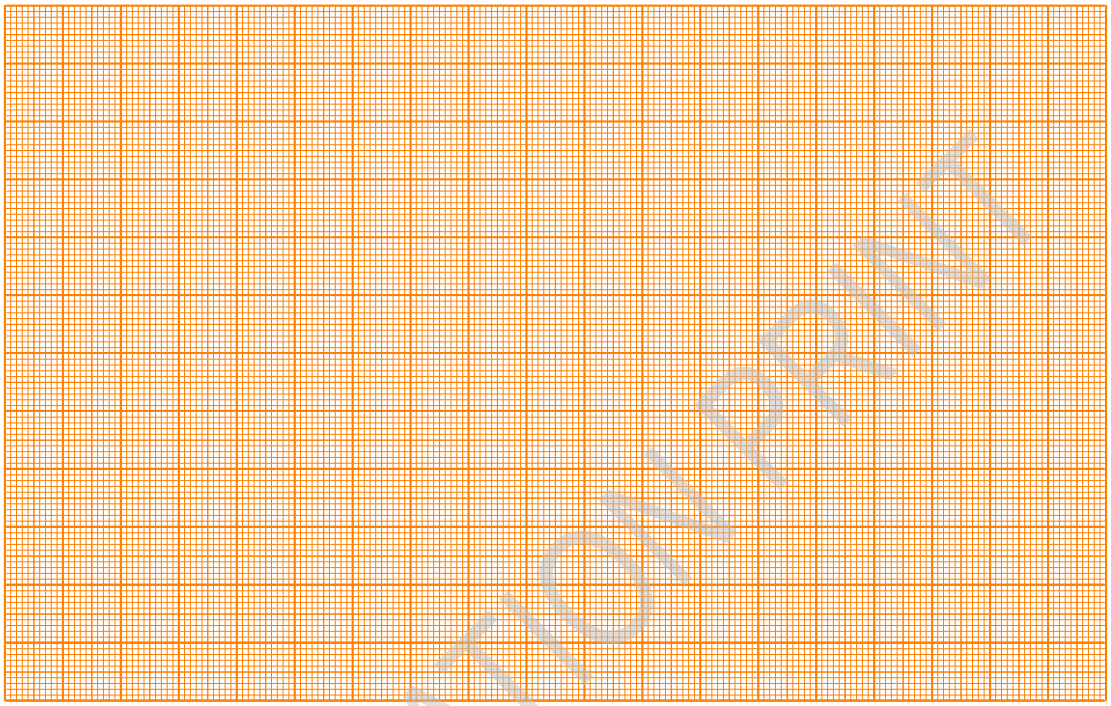
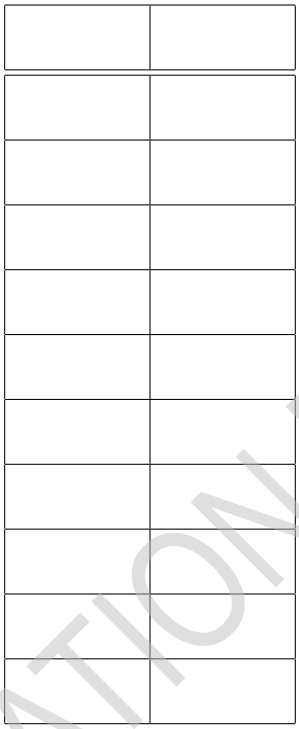
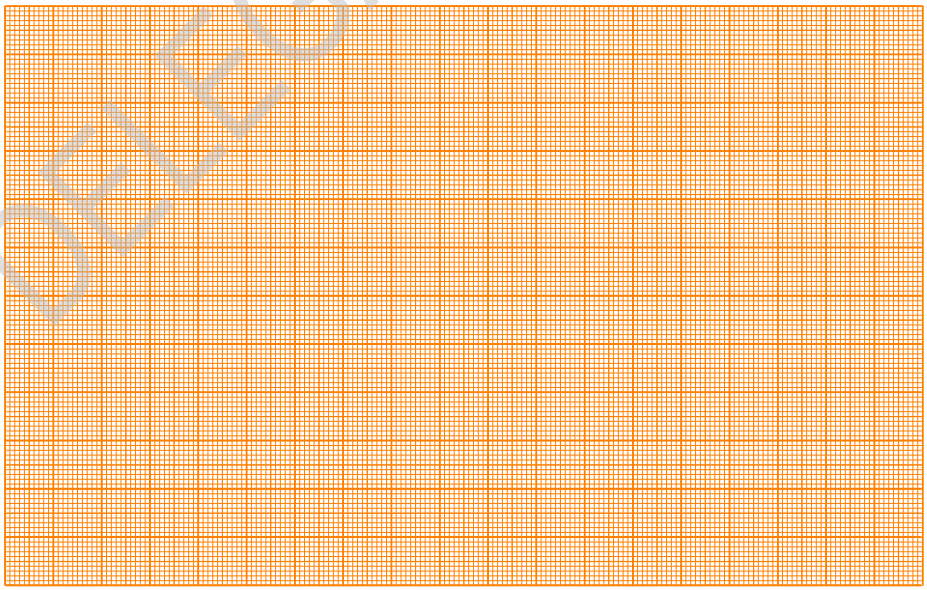
B.5 (0.5 pt)



B.6 (0.5 pt)





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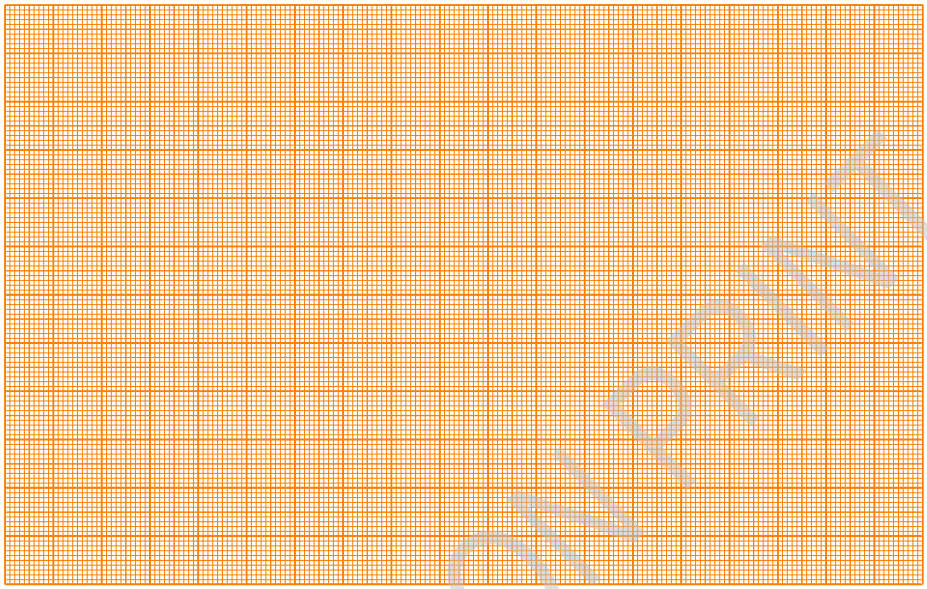
A1-11

Austrian German (Austria)

B.7 (0.3 pt)



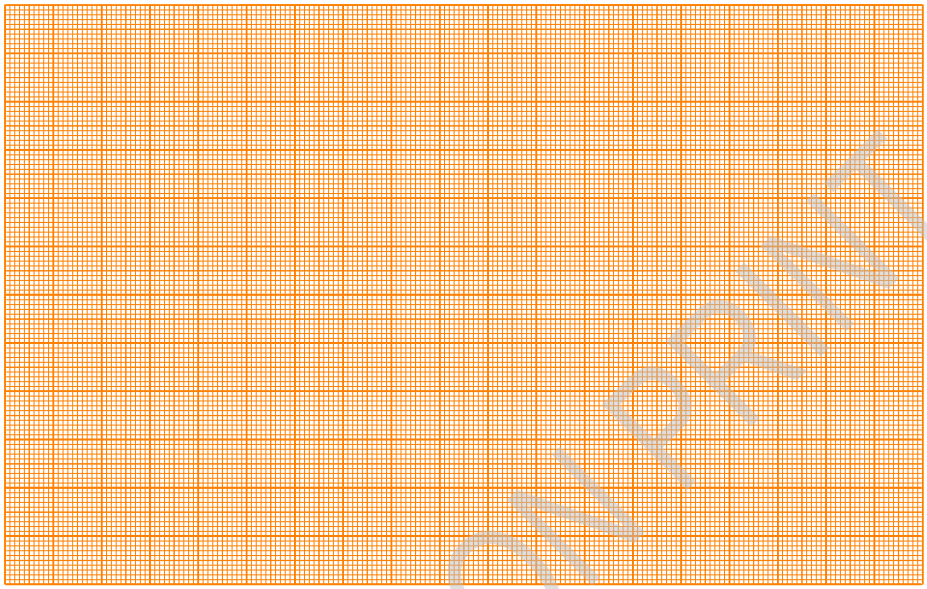
B.8 (0.4 pt)

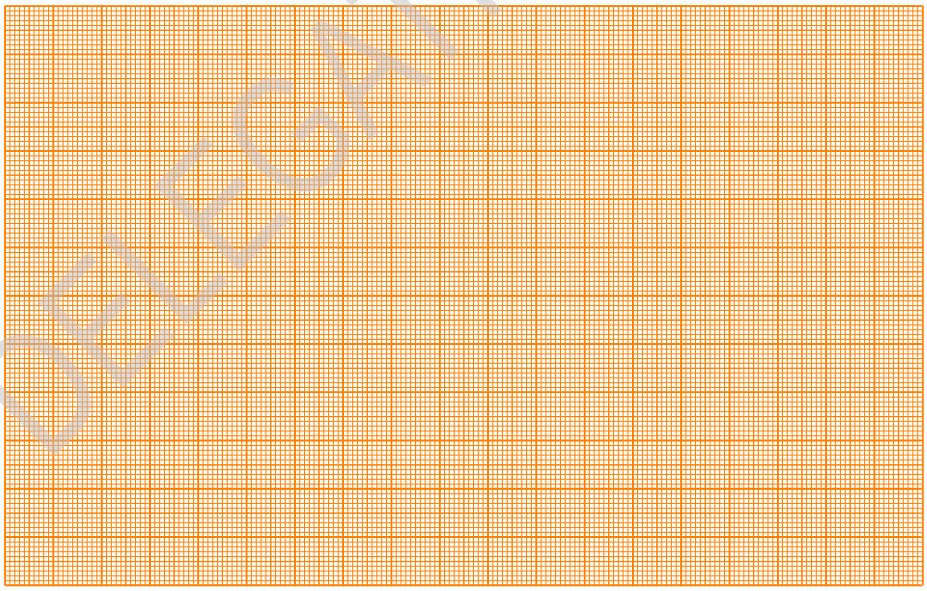
B.9 (0.4 pt)

Teil C: Dünnschichttransistor aus Papier (2,0 Punkte)

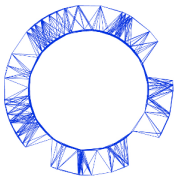
C.1 (0.8 pt)

C.2 (1.2 pt)





Teil D: Invertierer (1,5 Punkte)



A1-14

Austrian German (Austria)

D.1 (0.5 pt)

D.2 (0.5 pt)